SYMPOSIUM PROCEEDINGS

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March 30-April 1, 1993
UCLA
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Organized Jointly by:
The University of Michigan's NASA Center for Space Terahertz Technology and UCLA's Center for High Frequency Electronics.
Proceedings of the
FOURTH INTERNATIONAL SYMPOSIUM ON
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March 30-April 1, 1993

UCLA
Los Angeles, California

Symposium Co-chairs: Fawwaz T. Ulaby, University of Michigan
Tatsuo Itoh, UCLA

Technical Co-chairs: Gabriel M. Rebeiz, University of Michigan
Harold Fetterman, UCLA

Local Arrangements: Dorothy Treece, UCLA
David Binder, UCLA

Symposium Proceedings: Brenda Hadley, University of Michigan
Preface

The Fourth International Symposium on Space Terahertz Technology was held at UCLA in Los Angeles, California, on March 30-April 1, 1993. The Symposium, which was attended by approximately 150 scientists and engineers from the U.S., Europe, and Japan, featured papers relevant to the generation, detection, and use of the terahertz spectral region for space astronomy and remote sensing of the Earth's upper atmosphere. The program included thirteen sessions covering a wide variety of topics including solid-state oscillators, power-combining techniques, mixers, harmonic multipliers, antennas and antenna arrays, submillimeter receivers, and measurement techniques.

The Symposium was sponsored by the University Space Engineering Research Centers Program of NASA's Office of Advanced Concepts and Technology (OACT), and organized jointly by the University of Michigan's NASA Center for Space Terahertz Technology and UCLA's Center for High Frequency Electronics. The Microwave Theory and Techniques Society of IEEE served as a cooperative sponsor of the Symposium, as well as a medium for publication of some of the papers that were presented at the Symposium in the form of a mini-special issue (April 1994) of the IEEE-MTT Transactions.

The Fifth International Symposium on Space Terahertz Technology will be held at the University of Michigan in Ann Arbor, Michigan on May 10-12, 1994.

Fawwaz T. Ulaby
Tatsuo Itoh
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